

View Online at <https://aerobasegroup.com/nsn/5961-00-540-9621>

**Inclosure Material:**

Metal

**Overall Length:**

1.550 inches

**Overall Height:**

0.300 inches

**Overall Width:**

1.050 inches

**Function For Which Designed:**

Amplifier

**Mounting Facility Quantity:**

2

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Unthreaded hole

**Features Provided:**

Burn in

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

60.0 breakdown voltage, collector-to-base, emitter open all transistor and 60.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor

**Current Rating Per Characteristic:**

0.20 amperes source cutoff current all transistor and 10.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius ambient air

**Special Features:**

Internal junction configuration transistor pnp

**Terminal Type And Quantity:**

1 case and 2 pin

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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